NSN 5961-01-327-2856

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-327-2856 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** Between 0.250 inches and 0.450 inches Overall Width: 1.050 inches **Function For Which Designed:** Rectifier **Mounting Facility Quantity: Electrode Internally-electrically Connected To Case:** Cathode **Component Name And Quantity:** 2 semiconductor device diode **Mounting Method:** Unthreaded hole **Features Provided:** Burn in and hermetically sealed case **Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 500.0 reverse voltage, peak all semiconductor device diode **Current Rating Per Characteristic:** 25.00 amperes forward current, average absolute all semiconductor device diode and 200.00 amperes peak forward surge current nanoamperes all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: